








	DS1230AB-200	
	Hersteller-Teilenummer:	DS1230AB-200
	Hersteller / Marke:	Maxim Integrated
	Teil der Beschreibung:	IC NVSRAM 256K PARALLEL 28EDIP
	Datenblätter:	 DS1230AB-200.pdf
	RoHs Status:	Enthält Blei / RoHS nicht konform
	Lagerzustand:	New original, 30 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	DS1230AB-200
Hersteller	Maxim Integrated
Beschreibung	IC NVSRAM 256K PARALLEL 28EDIP
Kategorie	Integrierte Schaltungen (ICs) > Erinnerung
Teilstatus	30 pcs Stock
detaillierte Beschreibung	NVSRAM (Non-Volatile SRAM) Memory IC 256Kb (32K)
Serie	-
Technologie	NVSRAM (Non-Volatile SRAM)
Betriebstemperatur	0°C ~ 70°C (TA)
Befestigungsart	Through Hole
Verpackung / Gehäuse	28-DIP Module (0.600", 15.24mm)
Supplier Device-Gehäuse	28-EDIP
Spannungsversorgung	4.75 V ~ 5.25 V
Speichertyp	Non-Volatile
Speichergröße	256Kb (32K x 8)
Zugriffszeit	200ns
Speicherformat	NVSRAM
Schreibzyklus Zeit - Wort, Seite	200ns
Speicherschnittstelle	Parallel
Verpackung	Tube
Basisteilenummer	DS1230AB
Bleifreier Status / RoHS-Status	Contains lead / RoHS non-compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	DS1230AB200



















































DS1230AB-200 ist neu im Original, Suche DS1230AB-200 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DS1230AB-200 Maxim Integrated mit Garantie und Vertrauen.
Anfrage DS1230AB-200: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>DS1230AB-120IND+ Maxim Integrated IC NVSRAM 256KBIT 120NS 28EDIP</p>	 <p>DS1230AB-200IND+ DALLAS DALLAS DIP</p>	 <p>DS1230AB-200IND Maxim Integrated IC NVSRAM 256KBIT 200NS 28EDIP</p>	 <p>DS1230AB-200+ Maxim Integrated IC NVSRAM 256KBIT 200NS 28EDIP</p>
 <p>DS1230AB-120+ Maxim Integrated IC NVSRAM 256K PARALLEL 28EDIP</p>	 <p>DS1230AB-70 Maxim Integrated IC NVSRAM 256KBIT 70NS 28EDIP</p>	 <p>DS1230AB-150+ Maxim Integrated IC NVSRAM 256KBIT 150NS 28EDIP</p>	 <p>DS1230AB-120IND Maxim Integrated IC NVSRAM 256K PARALLEL 28EDIP</p>

heiße Teile

Mehr

 DS1216-0041E1	 DS1216AGTA-6B-E	 DS1216BXTA75TI	 DS1218S+TR	 DS1220AB-100IND
 DS1220AD-150	 DS1220Y-100	 DS1220Y-100IND+	 DS1220Y-120	 DS1220Y-120+
 DS1220Y-150	 DS1220Y-150+	 DS1220Y-200+	 DS1220Y-70	 DS1220Y-70IND
 DS1225AD-150+	 DS1225AD-170	 DS1225AD-70+	 DS1225AD-85	 DS1225Y-150
 DS1225Y-150IND	 DS1225Y-200	 DS1225Y-200+	 DS1227E+T&R	 DS1228S+
 DS1230AB-70	 DS1230WP-100	 DS1230Y-100	 DS1230Y-100+	 DS1230Y-120IND
 DS1230Y-150+	 DS1230Y-200+	 DS1230Y-70+	 DS1231-20	 DS1231S-20+
 DS1231S-20/TR	 DS1231S-20N	 DS1231S-35+	 DS1231S-35+TR	 DS1231S-50+
 DS1232AA-75	 DS1232CPA	 DS1232L+	 DS1232LN	 DS1232LP
 DS1232LP+	 DS1232LPN	 DS1232LPS	 DS1232LPS-2	 DS1232LPS-2+

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